

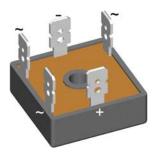
Standard Rectifier Module

| 3~ Rectifier | | | |
|------------------|---|--------|--|
| V_{RRM} | = | 1400 V | |
| I_{DAV} | = | 20 A | |
| I _{FSM} | = | 380 A | |

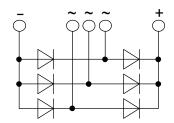
3~ Rectifier Bridge

Part number

VUO25-14NO8







Features / Advantages:

- Planar passivated chips
- Very low leakage currentVery low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For three phase bridge configurations
 Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: FO-B

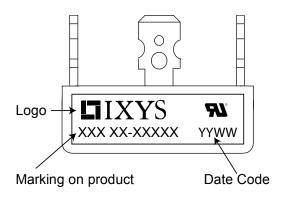
- Industry standard outline
- RoHS compliant
- 1/4" fast-on terminals
- Easy to mount with one screw



| Rating | s | |
|--------|------|--|
| . typ. | max. | Unit |
| | 1500 | V |
| | 1400 | V |
| | 40 | μΑ |
| | 1.5 | mΑ |
| | 1.05 | V |
| | 1.25 | V |
| | 0.94 | V |
| | 1.21 | V |
| | 20 | Α |
| | | |
| | 0.77 | V |
| | 14.2 | mΩ |
| | 8 | K/W |
| 1 | | K/W |
| | 15 | W |
| | 380 | Α |
| | 410 | Α |
| | 325 | Α |
| | 350 | Α |
| | 720 | A²s |
| | 700 | A²s |
| | 530 | A²s |
| | 510 | A²s |
| 10 |) | pF |
| | | 1 380 410 325 350 720 700 530 |



| Package FO-B | | | | Ratings | | | | |
|----------------------|--|---------------------|---|---------|------|------|------|------|
| Symbol | Definition | Conditions | | | min. | typ. | max. | Unit |
| I _{RMS} | RMS current | rrent per terminal | | | | 100 | Α | |
| T _{stg} | storage temperature | storage temperature | | | | | 125 | °C |
| T _{VJ} | virtual junction temperature | | | -40 | | 150 | °C | |
| Weight | | | | | | 20 | | g |
| M _D | mounting torque | mounting torque | | 1.8 | | 2.2 | Nm | |
| d _{Spp/App} | creepage distance on surface striking distance through air | | terminal to terminal | 9.0 | 7.0 | | | mm |
| d _{Spb/Apb} | | | terminal to backside | 10.0 | 10.0 | | | mm |
| V _{ISOL} | isolation voltage t = 1 | | | | 3000 | | | V |
| .002 | | t = 1 minute | 50/60 Hz, RMS; I _{ISOL} ≤ 1 mA | | 2500 | | | V |

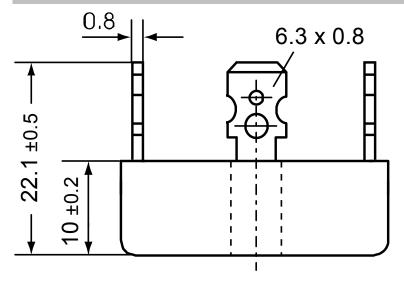


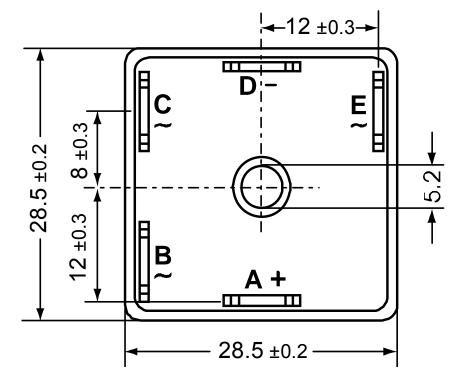
| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VUO25-14NO8 | VUO25-14NO8 | Box | 50 | 465119 |

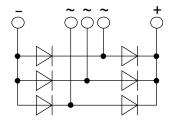
| Equiva | alent Circuits for | Simulation | * on die level | T _{VJ} = 150 °C |
|---------------------|--------------------|------------|----------------|--------------------------|
| $I \rightarrow V_0$ | R_0 | Rectifier | | |
| V _{0 max} | threshold voltage | 0.77 | | V |
| $R_{0\text{max}}$ | slope resistance * | 13 | | $m\Omega$ |



Outlines FO-B

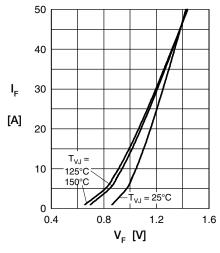


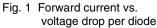






Rectifier





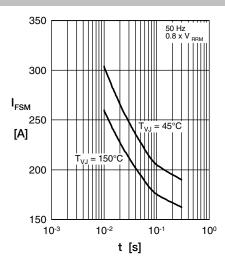


Fig. 2 Surge overload current vs. time per diode

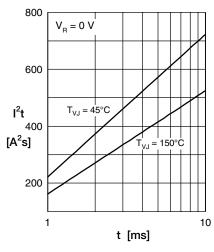


Fig. 3 I²t vs. time per diode

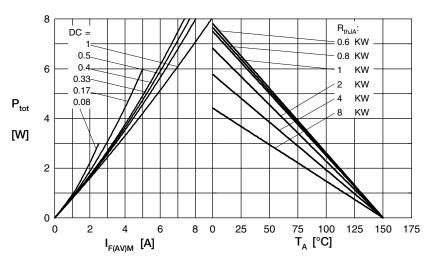


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

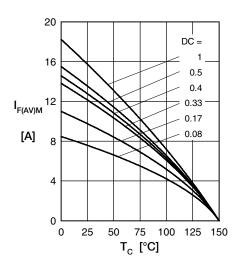


Fig. 5 Max. forward current vs. case temperature per diode

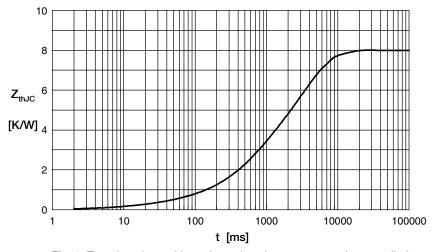


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

| i | R_{th} (K/W) | t _i (s) |
|---|----------------|--------------------|
| 1 | 0.040 | 0.005 |
| 2 | 0.250 | 0.030 |
| 3 | 1.810 | 0.500 |
| 4 | 5.900 | 3.200 |